TEXAS INSTRUMENTS

OPA891
SBOSAI7A – NOVEMBER 2023 – REVISED JUNE 2024

OPAx891 180MHz, 0.95nV/√Hz, Ultra-Low THD Operational Amplifiers

1 Features

- Ultra-low 0.95nV/√Hz voltage noise
- High speed:
  - 180MHz unity gain bandwidth
  - 140MHz bandwidth at a gain of 2V/V (–1V/V)
  - 105V/µs slew rate
- Very low distortion
  - THD = –91dBc (f = 1MHz, R_L = 150Ω)
  - THD = –100dBc (f = 1MHz, R_L = 1kΩ)
  - THD+N = –137dBc (f = 1kHz, BW = 80kHz)
- Low 0.2mV (typical) and 1mV (maximum) input offset voltage at 25°C
- 200mA output current drive (typical)
- Typical operation from ±4.5V to ±18V
- Offset nulling pins on the OPA891

2 Applications

- Low-noise, wide-band amplifier for industrial applications
- Voltage-controlled oscillators
- Active filters
- Video amplifiers
- Cable drivers
- Ultrasound scanners
- Vector signal transceiver (VST)
- Professional audio mixer or control surface
- Professional microphones and wireless systems
- Professional speaker systems
- Professional audio amplifier
- Soundbar
- Turntable
- Professional video camera
- Guitar and other instrument amplifier
- Data acquisition (DAQ)

3 Description

The OPA891 and OPA2891 (OPAx891) are ultra-low voltage noise, high-speed voltage feedback amplifiers that are an excellent choice for applications requiring low voltage noise, including communications and imaging. The single-amplifier OPA891 and the dual-amplifier OPA2891 offer very good ac performance with 140MHz bandwidth, gain (G) = 2V/V, 105V/µs slew rate, and 70ns settling time (0.1%). The OPAx891 are unity-gain stable with 180MHz bandwidth. These amplifiers have a high drive capability of 200mA and draw only 7.5mA supply current per channel. With –100dBc of total harmonic distortion (THD) at f = 1MHz and a very low noise of 0.95nV/√Hz, the OPAx891 are designed for applications requiring low distortion and low noise such as buffering analog-to-digital converters.
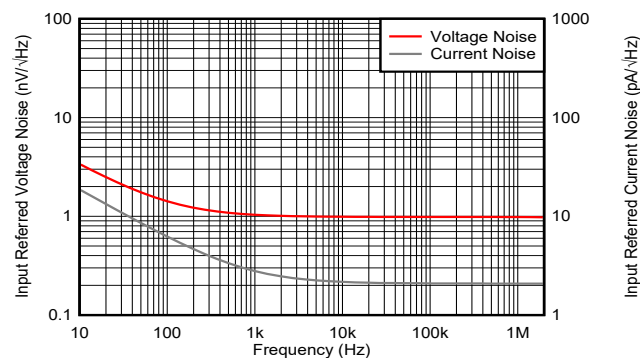
Device Information

PART NUMBER	AMPLIFIERS	PACKAGE[1]	PACKAGE SIZE[2]
OPA891	One	D (SOIC, 8)	4.9mm × 6mm
		DGN (HVSSOP, 8)	3mm × 4.9mm
OPA2891 [3]	Two	D (SOIC, 8)	4.9mm × 6mm
		DGN (HVSSOP, 8)	3mm × 4.9mm

(1) For more information, see Section 10.
(2) The package size (length × width) is a nominal value and includes pins, where applicable.
(3) Preview information (not Production Data).
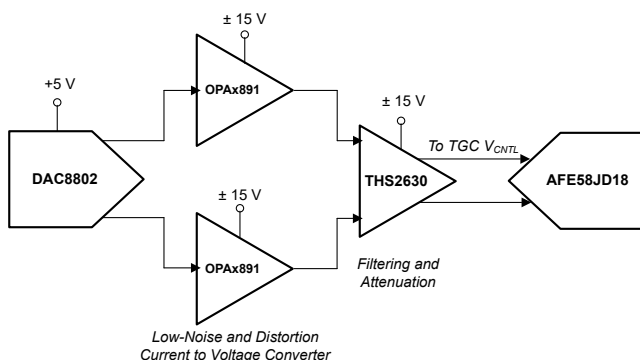
Ultrasound Time-Gain-Control Circuit

Voltage and Current Noise vs Frequency

Table of Contents

4 Pin Configuration and Functions

Figure 4-1. OPA891: D Package, 8-Pin SOIC, or DGN Package, 8-pin HVSSOP (Top View)

Table 4-1. Pin Functions: OPA891

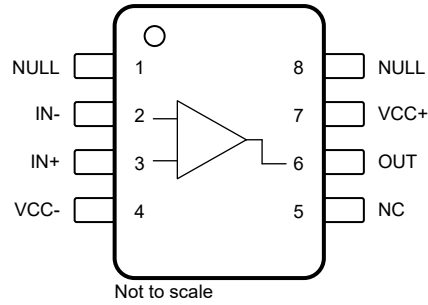| PIN		TYPE	DESCRIPTION
NAME	NO.		
IN–	2	Input	Inverting input
IN+	3	Input	Non-inverting input
NC	5	—	No connection
NULL	1, 8	Input	Voltage offset adjust
OUT	6	Output	Output of amplifier
VCC–	4	—	Negative power supply
VCC+	7	—	Positive power supply
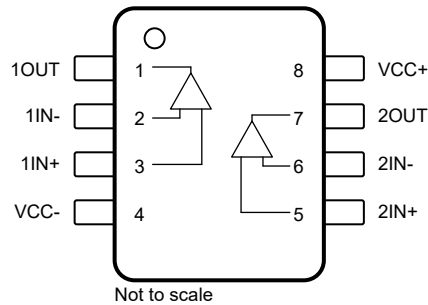
Figure 4-2. OPA2891: D Package, 8-Pin SOIC, or DGN Package, 8-pin HVSSOP (Top View)

Table 4-2. Pin Functions: OPA2891

PIN		TYPE	DESCRIPTION
NAME	NO.		
1IN–	2	Input	Channel 1 inverting input
1IN+	3	Input	Channel 1 non-inverting input
1OUT	1	Output	Channel 1 output
2IN–	6	Input	Channel 2 inverting input
2IN+	5	Input	Channel 2 non-inverting input
2OUT	7	Output	Channel 2 output
VCC–	4	—	Negative power supply
VCC+	8	—	Positive power supply

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[1]

			MIN	MAX	UNIT
V_{CC}	Supply voltage, $V_{CC+} - V_{CC-}$			37	V
V_I	Input voltage			$\pm V_{CC}$	V
I_O	Output current[2]			240	mA
V_{IO}	Differential input voltage			± 1.5	V
I_{IN}	Continuous input current			10	mA
T_A	Operating free-air temperature		−40	85	°C
T_J	Junction temperature	Any condition		150	°C
		Maximum junction temperature, continuous operation, long-term reliability[3]		125	
T_{stg}	Storage temperature		−65	150	°C

(1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
(2) When continuously operating at any output current, do not exceed the maximum junction temperature. Keep the output current less than the absolute maximum rating regardless of time interval.
(3) The maximum junction temperature for continuous operation is limited by package constraints. Operation greater than this temperature can result in reduced reliability, lifetime of the device, or both.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins[1]	±4000	V
		Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002, all pins[2]	±1500	

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage	Dual-supply	±4.5	±15	±18	V
		Single-supply	9	30	36	
T_A	Operating free-air temperature		−40	25	85	°C

Product Folder Links: *OPA891*

5.4 Thermal Information - OPA891

THERMAL METRIC[1]		OPA891		UNIT
		D (SOIC)	DGN (HVSSOP)	
		8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	124.5	60.7	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	65.0	87.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	72.2	33	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	13.6	7.9	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	71.3	32.9	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	17.2	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

5.5 Thermal Information - OPA2891

THERMAL METRIC[1]		OPA2891		UNIT
		D (SOIC)	DGN (HVSSOP)	
		8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	121.2	56.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	72.8	48.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	61.4	37.7	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	18.2	2.5	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	61	37.5	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	9.9	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

5.6 Electrical Characteristics - R_L = 150Ω

at T_A = 25°C, V_{CC} = ±15V, and R_L = 150Ω (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
DYNAMIC PERFORMANCE							
BW	Small-signal bandwidth (–3dB)	Gain = –1V/V or 2V/V	V_{CC} = ±15V		140		MHz
			V_{CC} = ±5V		135		
	Bandwidth for 0.1dB flatness	Gain = –1V/V or 2V/V	V_{CC} = ±15V		9		MHz
			V_{CC} = ±5V		9		
SR	Slew rate[1]	Gain = –1V/V	V_{CC} = ±15V, 20V step		105		V/µs
			V_{CC} = ±5V, 5V step		90		
t_S	Settling time	To 0.1%, gain = –1V/V	V_{CC} = ±15V, 5V step		70		ns
			V_{CC} = ±5V, 2.5V step		55		
		To 0.01%, gain = –1V/V	V_{CC} = ±15V, 5V step		90		
			V_{CC} = ±5V, 2.5V step		80		
AUDIO PERFORMANCE							
THD+N	Total harmonic distortion + noise	Gain = 1V/V, R_L = 600Ω, f = 1kHz, BW = 80kHz	V_{CC} = ±15V, V_O = 3V_{RMS}		–137		dB
					0.000014		%
			V_{CC} = ±5V, V_O = 1V_{RMS}		–130		dB
					0.00003		%
		Gain = 2V/V, R_L = 600Ω, f = 1kHz, BW = 80kHz	V_{CC} = ±15V, V_O = 3V_{RMS}		–133		dB
					0.000022		%
			V_{CC} = ±5V, V_O = 1V_{RMS}		–124		dB
					0.00006		%
IMD	Intermodulation distortion	Gain = 1V/V, R_L = 600Ω, SMPTE/DIN two-tone, 4:1 (60Hz and 7kHz)	V_{CC} = ±15V, V_O = 3V_{RMS}		–130		dB
					0.000032		%
			V_{CC} = ±5V, V_O = 1V_{RMS}		–126		dB
					0.00005		%
		Gain = 2V/V, R_L = 600Ω, SMPTE/DIN two-tone, 4:1 (60Hz and 7kHz)	V_{CC} = ±15V, V_O = 3V_{RMS}		–126		dB
					0.00005		%
			V_{CC} = ±5V, V_O = 1V_{RMS}		–120		dB
					0.0001		%
NOISE AND DISTORTION PERFORMANCE							
THD	Total harmonic distortion	Gain = 2V/V, V_{CC} = ±5V or ±15V, f = 1MHz $V_{O(pp)}$ = 2V			–91		dBc
V_n	Input voltage noise	V_{CC} = ±5V or ±15V, f > 10kHz			0.95		nV/√Hz
I_n	Input current noise	V_{CC} = ±5V or ±15V, f > 10kHz			2.3		pA/√Hz
	Channel-to-channel crosstalk (OPA2891 only)	V_{CC} = ±5V or ±15V, f = 1MHz			–80		dBc
DC PERFORMANCE							
V_{OS}	Input offset voltage	V_{CC} = ±5V or ±15V, T_A = 25°C			0.2	1	mV
	Offset voltage drift	V_{CC} = ±5V or ±15V, T_A = full range			1		µV/°C
I_{IB}	Input bias current	V_{CC} = ±5V or ±15V	T_A = 25°C		9	20	µA
			T_A = full range			33	
I_{OS}	Input offset current	V_{CC} = ±5V or ±15V	T_A = 25°C		30	250	nA
			T_A = full range			400	

Product Folder Links: *OPA891*

5.6 Electrical Characteristics - R$_L$ = 150Ω (continued)

at T$_A$ = 25°C, V$_{CC}$ = ±15V, and R$_L$ = 150Ω (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
INPUT CHARACTERISTICS							
V$_{ICR}$	Common-mode input voltage range	V$_{CC}$ = ±15V		±13.8	±14.3		V
		V$_{CC}$ = ±5V		±3.8	±4.3		
CMRR	Common-mode rejection ratio	V$_{CC}$ = ±15V, V$_{ICR}$ = ±12V	T$_A$ = 25°C	85	104		dB
			T$_A$ = full range	80			
		V$_{CC}$ = ±5V, V$_{ICR}$ = ±2.5V	T$_A$ = 25°C	90	106		
			T$_A$ = full range	85			
	Input impedance	Common-mode			10 || 1.2		MΩ || pF
		Differential-mode			6 || 1.8		kΩ || pF
OUTPUT CHARACTERISTICS							
V$_O$	Output voltage swing	V$_{CC}$ = ±15V, R$_L$ = 250Ω		±12	±12.9		V
		V$_{CC}$ = ±5V		±3	±3.5		
I$_O$	Output current[2]	R$_L$ = 10Ω	V$_{CC}$ = ±15V	160	200		mA
			V$_{CC}$ = ±5V	120	160		
R$_O$	Output resistance	Open loop			5		Ω
POWER SUPPLY							
V$_{CC}$	Supply voltage	Dual supply		±4.5		±18	V
		Single supply		9		36	
I$_{CC}$	Supply current (each amplifier)	V$_{CC}$ = ±15V	T$_A$ = 25°C		7.5	10	mA
			T$_A$ = full range			11	
		V$_{CC}$ = ±5V	T$_A$ = 25°C		6.5	9	
			T$_A$ = full range			10	
PSRR	Power-supply rejection ratio	V$_{CC}$ = ±5V or ±15V, T$_A$ = 25°C		90	105		dB
		V$_{CC}$ = ±5V or ±15V, T$_A$ = full range		85			

(1) Slew rate is measured from an output level range of 25% to 75%.
(2) Keep junction temperature less than the absolute maximum rating when the output is heavily loaded or shorted; see also *Section 5.1*.

5.7 Electrical Characteristics - R$_L$ = 1kΩ

at T$_A$ = full range, V$_{CC}$ = ±15V, and R$_L$ = 1kΩ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
DYNAMIC PERFORMANCE							
BW	Unity gain bandwidth	V$_{CC}$ = ±15V, closed loop			180		MHz
	Small-signal bandwidth (−3dB)	Gain = −1V/V or 2V/V	V$_{CC}$ = ±15V		140		MHz
			V$_{CC}$ = ±5V		135		
	Bandwidth for 0.1dB flatness	Gain = −1V/V or 2V/V	V$_{CC}$ = ±15V		9		MHz
			V$_{CC}$ = ±5V		9		
	Full power bandwidth[1]	V$_{CC}$ = ±15V, V$_{O(pp)}$ = 20V			1.7		MHz
		V$_{CC}$ = ±5V, V$_{O(pp)}$ = 5V			5.7		
SR	Slew rate				105		V/µs
t$_S$	Settling time	To 0.1%, gain = −1V/V	V$_{CC}$ = ±15V, 5V step		70		ns
			V$_{CC}$ = ±5V, 2.5V step		55		
		To 0.01%, gain = −1V/V	V$_{CC}$ = ±15V, 5V step		90		
			V$_{CC}$ = ±5V, 2.5V step		80		

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Product Folder Links: *OPA891*

5.7 Electrical Characteristics - R_L = 1kΩ (continued)

at T_A = full range, V_{CC} = ±15V, and R_L = 1kΩ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
AUDIO PERFORMANCE							
THD+N	Total harmonic distortion + noise	Gain = 1V/V, R_L = 2kΩ, f = 1kHz, BW = 80kHz	V_{CC} = ±15V, V_O = 3V_{RMS}		−137		dB
					0.000014		%
			V_{CC} = ±5V, V_O = 1V_{RMS}		−130		dB
					0.00003		%
		Gain = 2V/V, R_L = 2kΩ, f = 1kHz, BW = 80kHz	V_{CC} = ±15V, V_O = 3V_{RMS}		−133		dB
					0.000022		%
			V_{CC} = ±5V, V_O = 1V_{RMS}		−124		dB
					0.00006		%
IMD	Intermodulation distortion	Gain = 1V/V, R_L = 2kΩ, SMPTE/DIN two-tone, 4:1 (60Hz and 7kHz)	V_{CC} = ±15V, V_O = 3V_{RMS}		−130		dB
					0.000032		%
			V_{CC} = ±5V, V_O = 1V_{RMS}		−126		dB
					0.00005		%
		Gain = 2V/V, R_L = 2kΩ, SMPTE/DIN two-tone, 4:1 (60Hz and 7kHz)	V_{CC} = ±15V, V_O = 3V_{RMS}		−126		dB
					0.00005		%
			V_{CC} = ±5V, V_O = 1V_{RMS}		−120		dB
					0.0001		%
NOISE AND DISTORTION PERFORMANCE							
THD	Total harmonic distortion	Gain = 2V/V, V_{CC} = ±5V or ±15V, f = 1MHz $V_{O(pp)}$ = 2V			−100		dBc
DC PERFORMANCE							
	Open-loop gain	V_{CC} = ±15V, V_O = ±10V	T_A = 25°C	93	100		dB
			T_A = full range	92			
		V_{CC} = ±5V, V_O = ±2.5V	T_A = 25°C	92	98		
			T_A = full range	91			
V_{OS}	Input offset voltage	V_{CC} = ±5V or ±15V, T_A = 25°C			0.2	1	mV
	Offset voltage drift	V_{CC} = ±5V or ±15V, T_A = full range			1		μV/°C
I_{IB}	Input bias current	V_{CC} = ±5V or ±15V	T_A = 25°C		9	20	μA
			T_A = full range			33	
I_{OS}	Input offset current	V_{CC} = ±5V or ±15V	T_A = 25°C		30	250	nA
			T_A = full range			400	
	Input offset current drift	V_{CC} = ±5V or ±15V, T_A = full range			0.2		nA/°C
INPUT CHARACTERISTICS							
V_{ICR}	Common-mode input voltage range	V_{CC} = ±15V		±13.8	±14.3		V
		V_{CC} = ±5V		±3.8	±4.3		
CMRR	Common-mode rejection ratio	V_{CC} = ±15V, V_{ICR} = ±12V	T_A = 25°C	85	104		dB
			T_A = full range	80			
		V_{CC} = ±5V, V_{ICR} = ±2.5V	T_A = 25°C	90	106		
			T_A = full range	85			
	Input impedance	Common-mode			10 ‖ 1.2		MΩ ‖ pF
		Differential-mode			6 ‖ 1.8		kΩ ‖ pF
OUTPUT CHARACTERISTICS							
V_O	Output voltage swing	V_{CC} = ±15V		±13	±13.6		V
		V_{CC} = ±5V		±3.4	±3.8		
POWER SUPPLY							
PSRR	Power-supply rejection ratio	V_{CC} = ±5V or ±15V	T_A = 25°C	90	105		dB
			T_A = full range	85			

(1)   Full power bandwidth = slew rate / [π$V_{O(P-P)}$].

Product Folder Links: *OPA891*

5.8 Typical Characteristics

at T_A = 25°C, V_{CC} = ±15V, gain = +1V/V, R_L = 150Ω, and R_F = 300Ω (unless otherwise noted)

V_{CC} = ±15V, R_L = 150Ω, V_{OUT} = 200mV$_{PP}$
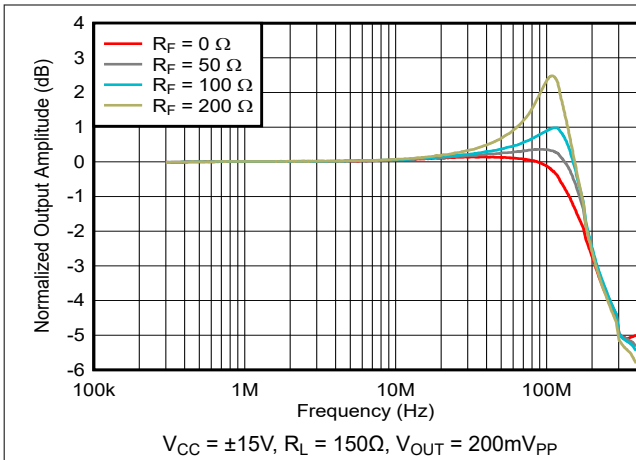
Figure 5-1. Frequency Response vs Feedback Resistance

V_{CC} = ±15V, R_L = 1kΩ, V_{OUT} = 200mV$_{PP}$
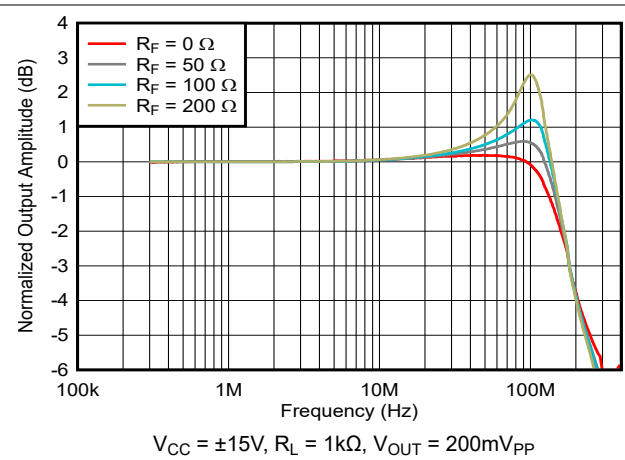
Figure 5-2. Frequency Response vs Feedback Resistance

V_{CC} = ±5V, R_L = 150Ω, V_{OUT} = 200mV$_{PP}$
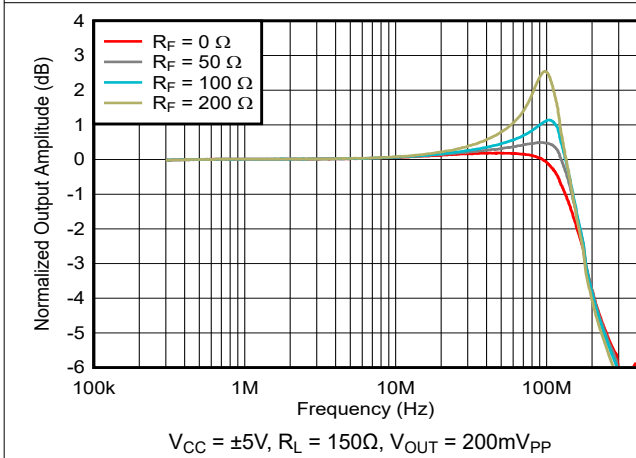
Figure 5-3. Frequency Response vs Feedback Resistance

V_{CC} = ±5V, R_L = 1kΩ, V_{OUT} = 200mV$_{PP}$
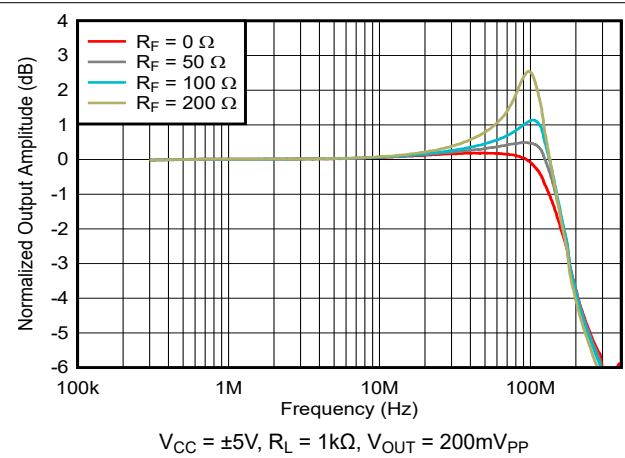
Figure 5-4. Frequency Response vs Feedback Resistance

Gain = +2V/V, V_{OUT} = 400mV$_{PP}$
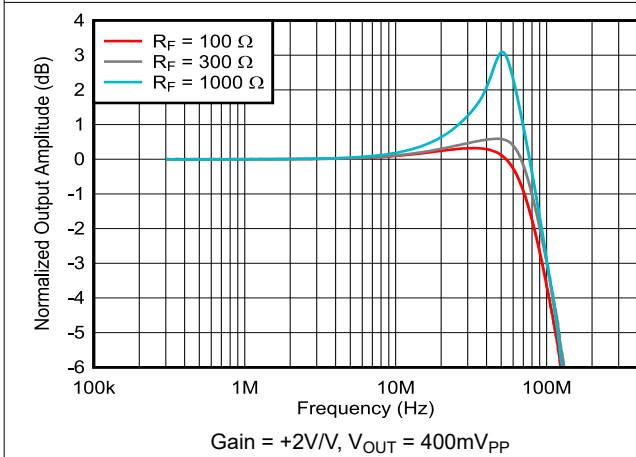
Figure 5-5. Frequency Response vs Feedback Resistance

V_{CC} = ±5V, gain = +2V/V, V_{OUT} = 400mV$_{PP}$
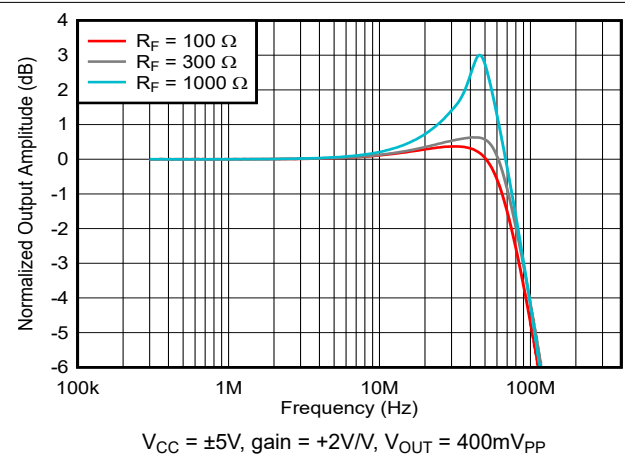
Figure 5-6. Frequency Response vs Feedback Resistance

5.8 Typical Characteristics (continued)

at T_A = 25°C, V_{CC} = ±15V, gain = +1V/V, R_L = 150Ω, and R_F = 300Ω (unless otherwise noted)

V_{CC} = ±15V
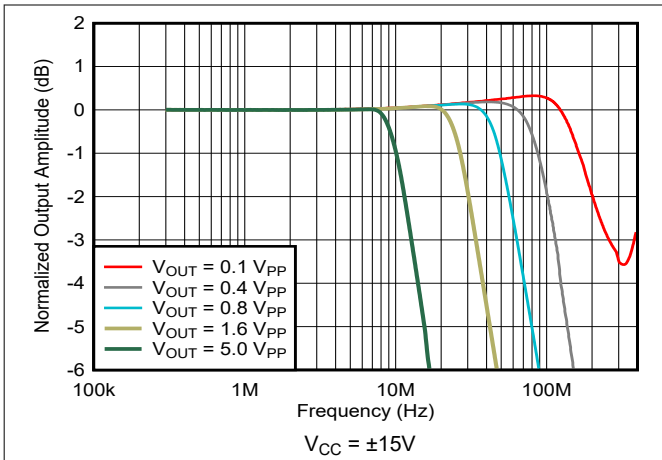
Figure 5-7. Large-signal Frequency Response

V_{CC} = ±5V
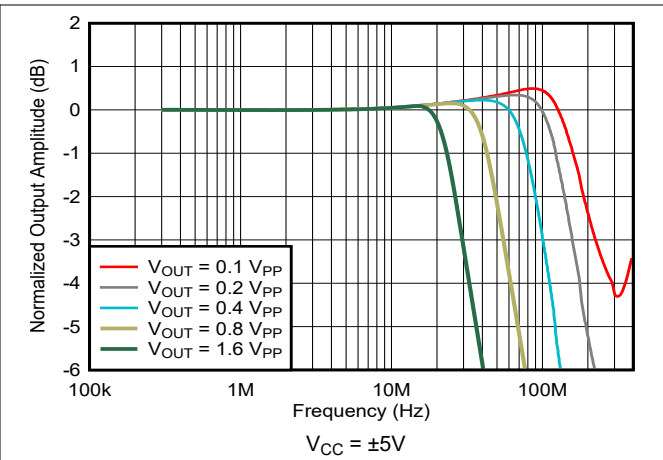
Figure 5-8. Large-signal Frequency Response
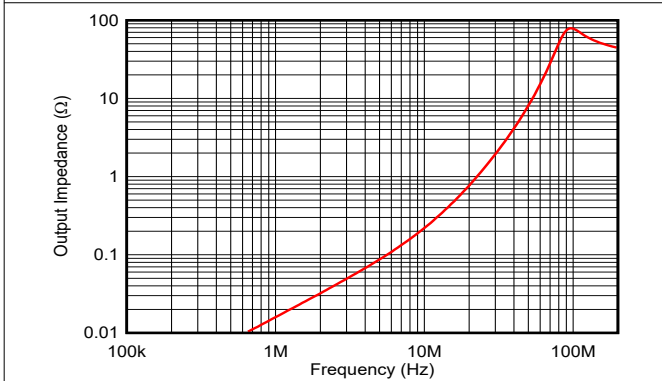
Figure 5-9. Closed-loop Output Impedance
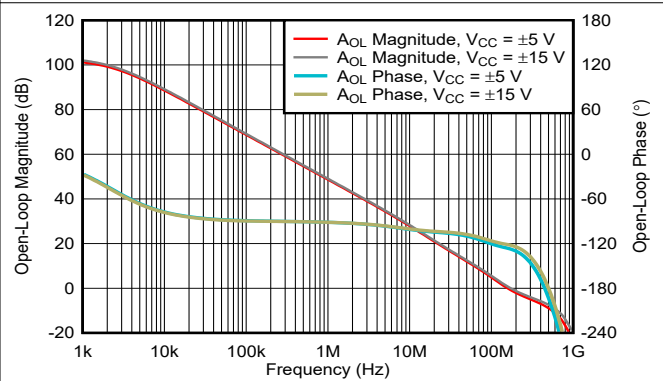
Figure 5-10. Open-loop Gain and Phase Response
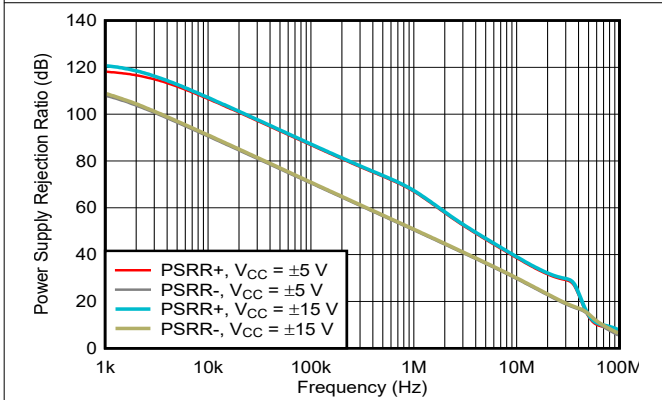
Figure 5-11. Power-supply Rejection Ratio vs Frequency
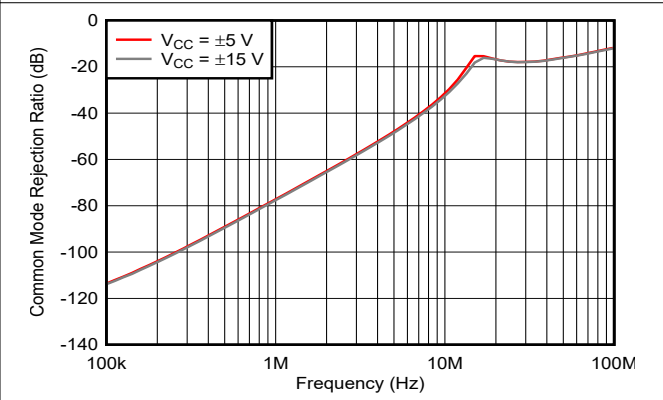
Figure 5-12. Common-mode Rejection Ratio vs Frequency

5.8 Typical Characteristics (continued)

at T_A = 25°C, V_{CC} = ±15V, gain = +1V/V, R_L = 150Ω, and R_F = 300Ω (unless otherwise noted)
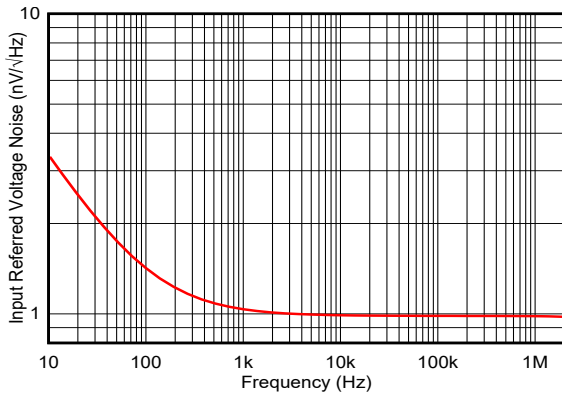
Figure 5-13. Input-Referred Voltage Noise vs Frequency
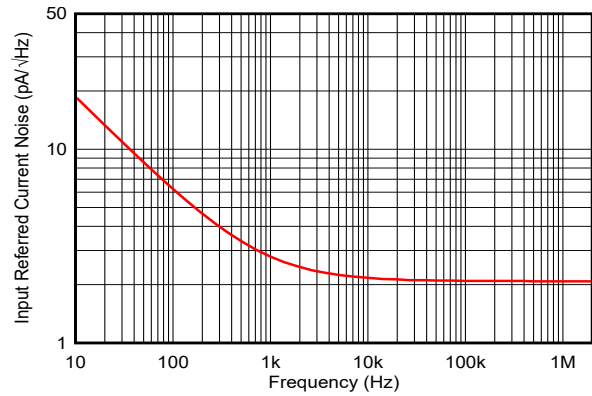
Figure 5-14. Input-Referred Current Noise vs Frequency

V_{CC} = ±15V, gain = +2V/V, R_L = 1kΩ, V_{OUT} = 2V_{PP}
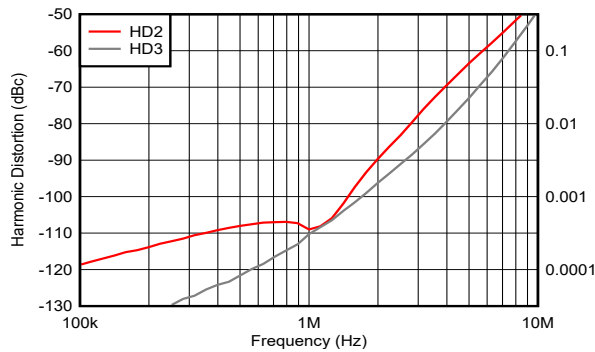
Figure 5-15. Harmonic Distortion vs Frequency

V_{CC} = ±5V, gain = +2V/V, R_L = 1kΩ, V_{OUT} = 2V_{PP}
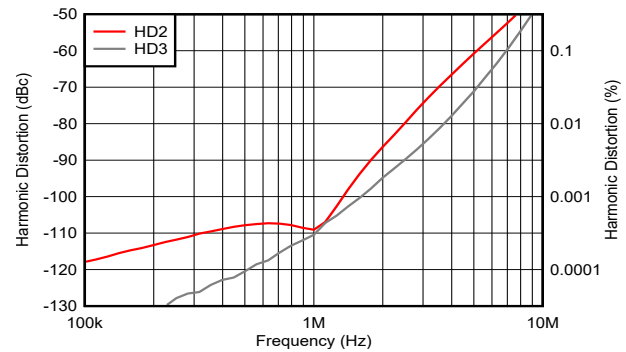
Figure 5-16. Harmonic Distortion vs Frequency

V_{CC} = ±15V, gain = +2V/V, R_L = 150Ω, V_{OUT} = 2V_{PP}
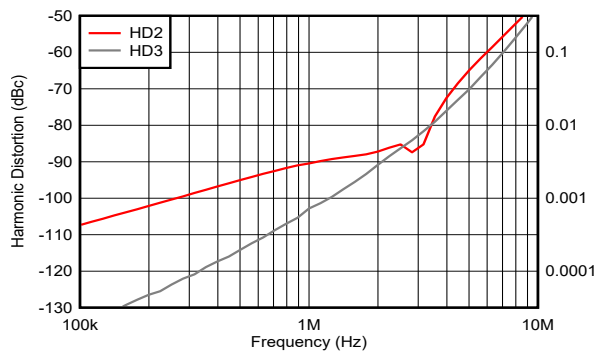
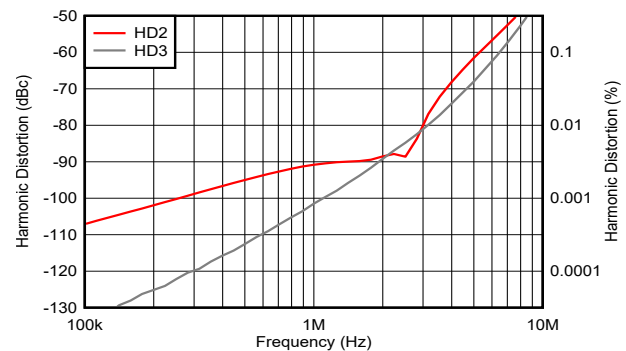**Figure 5-17. Harmonic Distortion vs Frequency**

V_{CC} = ±5V, gain = +2V/V, R_L = 150Ω, V_{OUT} = 2V_{PP}

Figure 5-18. Harmonic Distortion vs Frequency

Product Folder Links: *OPA891*

5.8 Typical Characteristics (continued)

at T_A = 25°C, V_{CC} = ±15V, gain = +1V/V, R_L = 150Ω, and R_F = 300Ω (unless otherwise noted)

V_{CC} = ±15V, gain = +5V/V, R_L = 1kΩ, f = 1MHz

Figure 5-19. Harmonic Distortion vs Peak-to-Peak Output Voltage

V_{CC} = ±15V, gain = +5V/V, R_L = 150Ω, f = 1MHz

Figure 5-20. Harmonic Distortion vs Peak-to-Peak Output Voltage

Gain = +2V/V

Figure 5-21. 1V Step Response

V_{CC} = ±5V, gain = −1V/V, R_F = 430Ω

Figure 5-22. 4V Step Response

Gain = +2V/V

Figure 5-23. 20V Step Response

3 typical units

Figure 5-24. Input Offset Voltage vs Ambient Temperature

Product Folder Links: *OPA891*

5.8 Typical Characteristics (continued)

at T_A = 25°C, V_{CC} = ±15V, gain = +1V/V, R_L = 150Ω, and R_F = 300Ω (unless otherwise noted)

μ = 0.209mV, σ = 0.0911mV
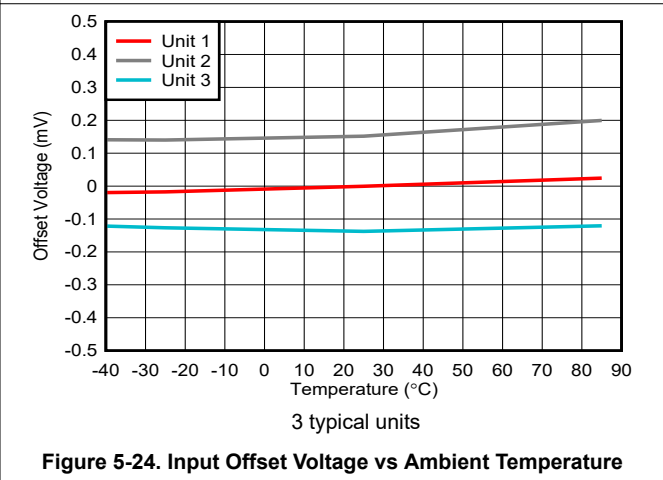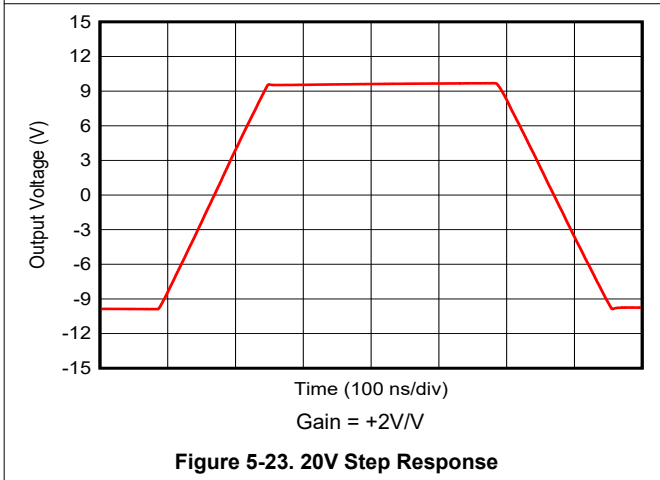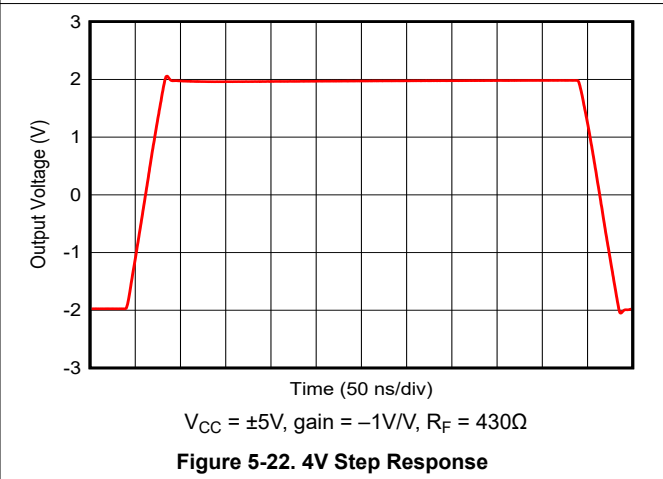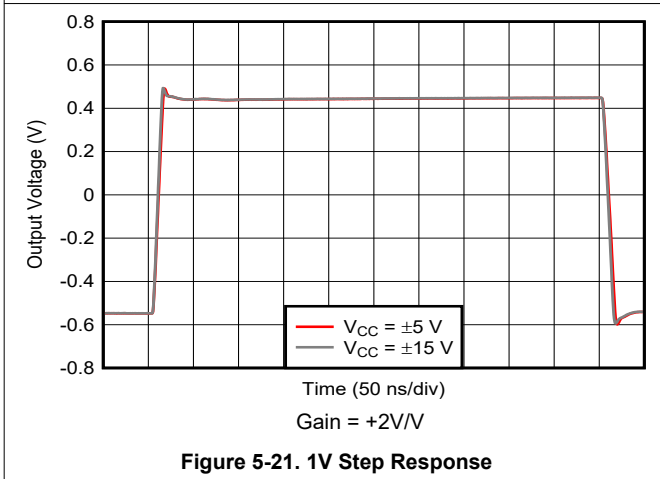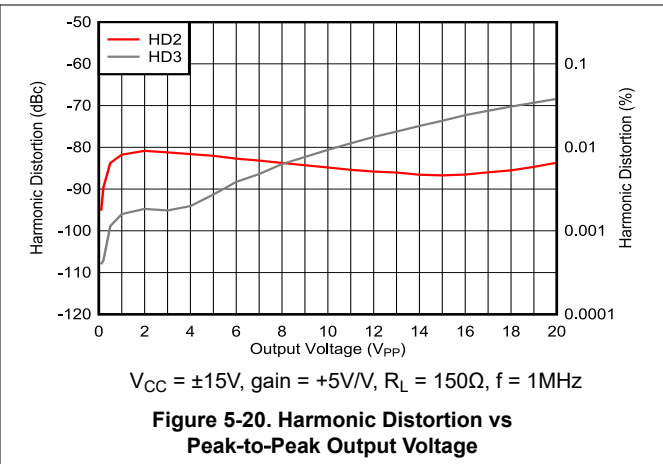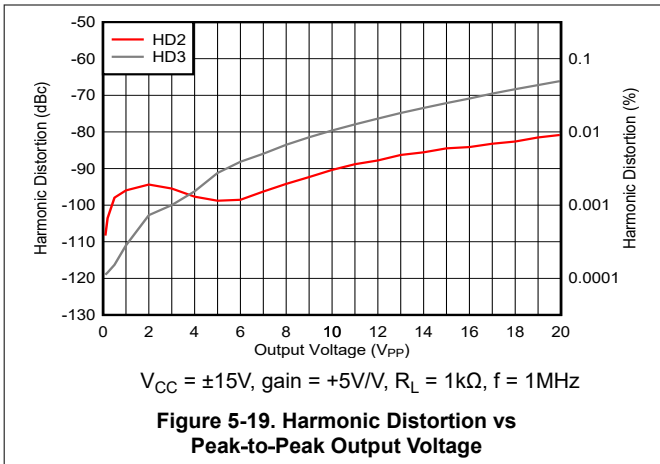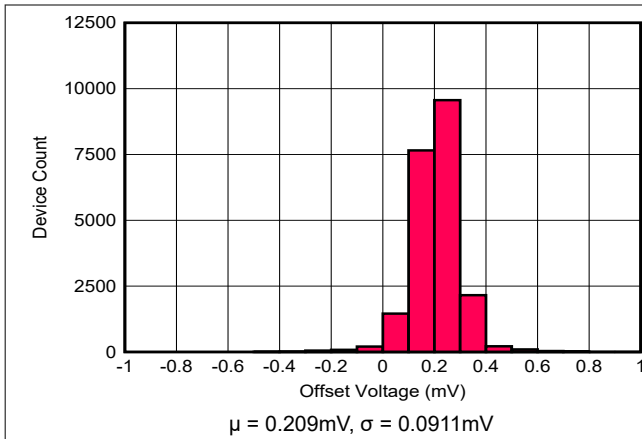
Figure 5-25. Voltage Offset Distribution

3 typical units
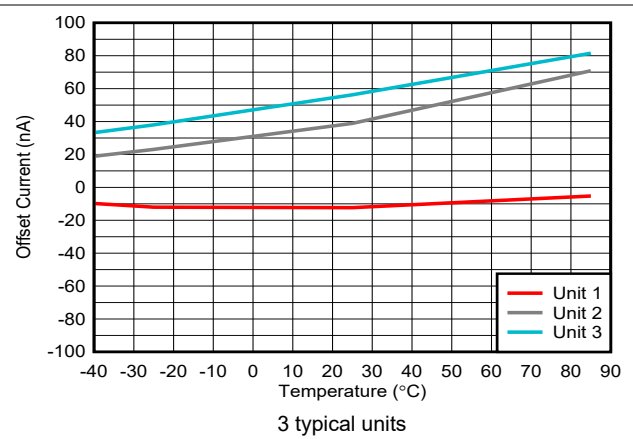
Figure 5-26. Input Offset Current vs Ambient Temperature
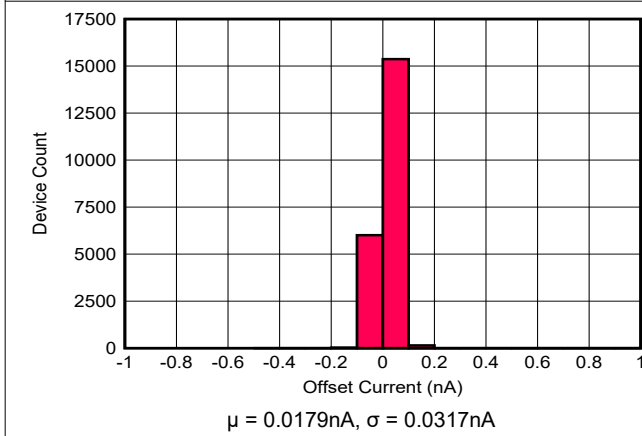

μ = 0.0179nA, σ = 0.0317nA

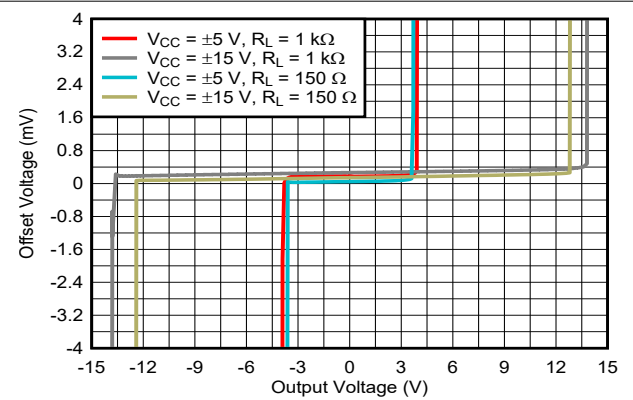**Figure 5-27. Input Offset Current vs Ambient Temperature**

Figure 5-28. Offset Voltage vs Output Voltage
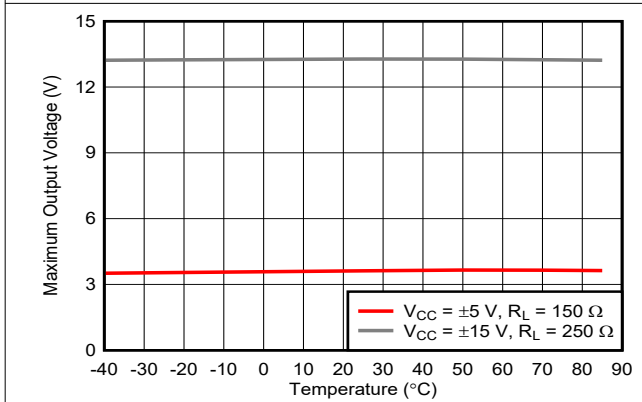
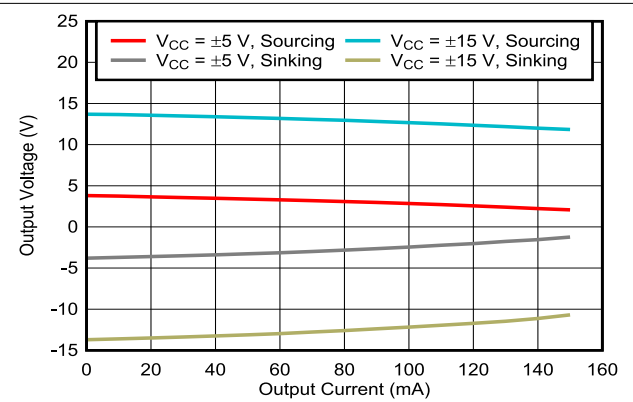**Figure 5-29. Maximum Output Voltage Swing vs Ambient Temperature**

Figure 5-30. Output Swing vs Load Current

Product Folder Links: *OPA891*

5.8 Typical Characteristics (continued)

at T_A = 25°C, V_{CC} = ±15V, gain = +1V/V, R_L = 150Ω, and R_F = 300Ω (unless otherwise noted)
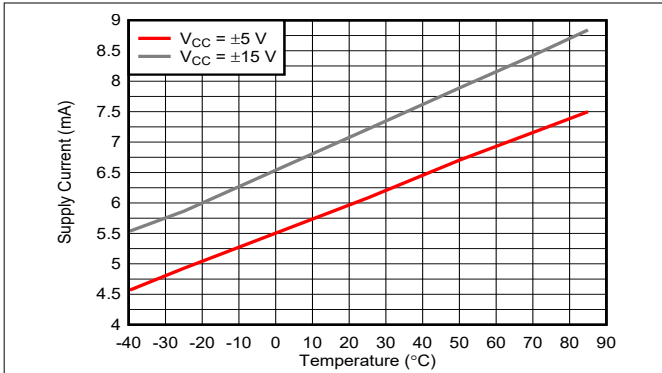
Figure 5-31. Supply Current vs Ambient Temperature
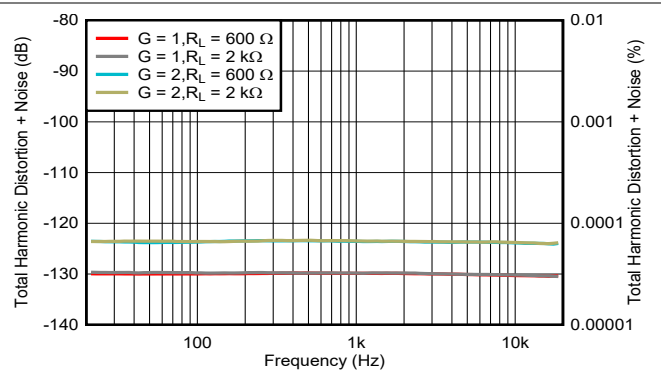
V_{CC} = ±5V, V_{OUT} = 1V_{RMS}, BW = 80kHz

Figure 5-32. THD+N vs Frequency
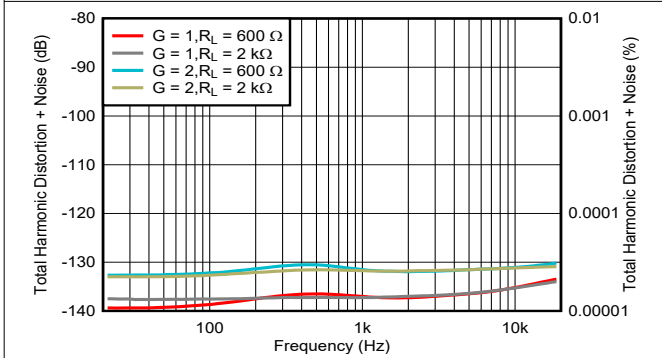
V_{CC} = ±15V, V_{OUT} = 3V_{RMS}, BW = 80kHz

Figure 5-33. THD+N vs Frequency
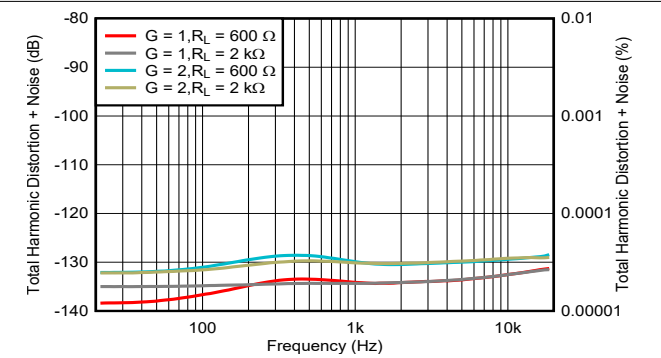
V_{CC} = ±18V, V_{OUT} = 3V_{RMS}, BW = 80kHz

Figure 5-34. THD+N vs Frequency
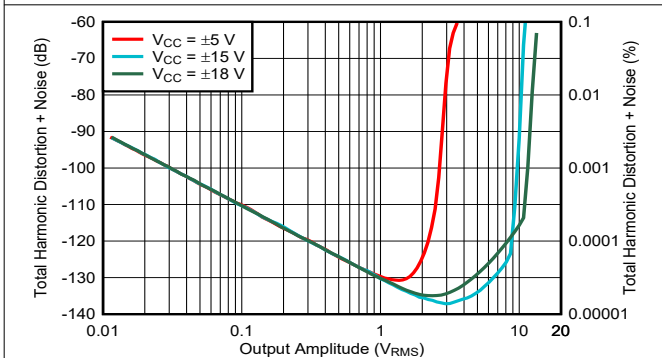
Gain = +1V/V, R_L = 2kΩ, f = 1kHz, BW = 80kHz

Figure 5-35. THD+N Ratio vs Output Amplitude
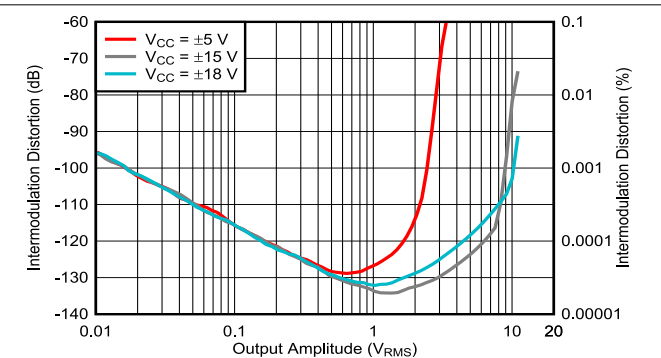
Gain = +1V/V, SMPTE/DIN two-tone 4:1 (60Hz and 7kHz), R_L = 2kΩ, BW = 80kHz

Figure 5-36. Intermodulation Distortion vs Amplitude

Product Folder Links: *OPA891*

5.8 Typical Characteristics (continued)

at T_A = 25°C, V_{CC} = ±15V, gain = +1V/V, R_L = 150Ω, and R_F = 300Ω (unless otherwise noted)

Gain = +2V/V, SMPTE/DIN two-tone 4:1 (60Hz and 7kHz),
R_L = 2kΩ, BW = 80kHz

Figure 5-37. Intermodulation Distortion vs Amplitude

Gain = +1V/V, V_{CC} = ±5V, V_{OUT} = 1V$_{RMS}$
R_L = 2kΩ, BW = 80kHz

Figure 5-38. Distortion Harmonics vs Frequency

Gain = +1V/V, V_{CC} = ±15V, V_{OUT} = 3V$_{RMS}$,
R_L = 2kΩ, BW = 80kHz

Figure 5-39. Distortion Harmonics vs Frequency

Gain = +1V/V, V_{CC} = ±18V, V_{OUT} = 3V$_{RMS}$,
R_L = 2kΩ, BW = 80kHz

Figure 5-40. Distortion Harmonics vs Frequency

Gain = +1V/V, V_{OUT} = 3V$_{RMS}$,
R_L = 2kΩ, f = 1kHz, BW = 80kHz

Figure 5-41. Distortion Harmonics vs Supply Voltage

Gain = +1V/V, V_{CC} = ±15V, V_{OUT} = 3V$_{RMS}$, R_L = 2kΩ

Figure 5-42. 1kHz Output Spectrum

Product Folder Links: OPA891

5.8 Typical Characteristics (continued)

at T_A = 25°C, V_{CC} = ±15V, gain = +1V/V, R_L = 150Ω, and R_F = 300Ω (unless otherwise noted)
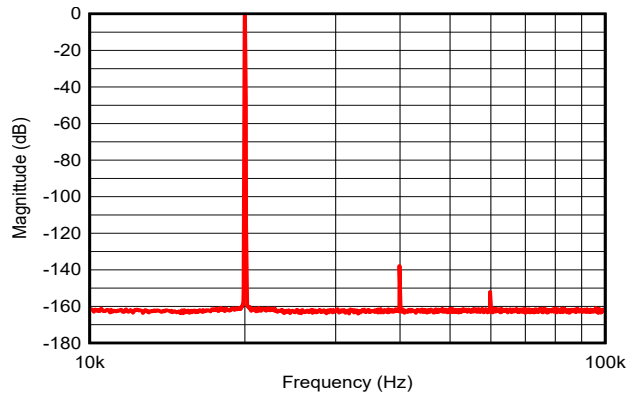
Gain = +1V/V, V_{CC} = ±5V, V_{OUT} = 1V_{RMS}, R_L = 2kΩ

Figure 5-43. 20kHz Output Spectrum

Product Folder Links: *OPA891*

6 Detailed Description

6.1 Overview

The OPAx891 is a high-speed operational amplifier configured in a voltage-feedback architecture. These amplifiers are built using a 36V, complementary bipolar process with NPN and PNP transistors that possess an f_T of several GHz. This configuration results in exceptionally high-performance amplifiers with wide bandwidth, high slew rate, fast settling time, and low distortion.

6.2 Functional Block Diagrams
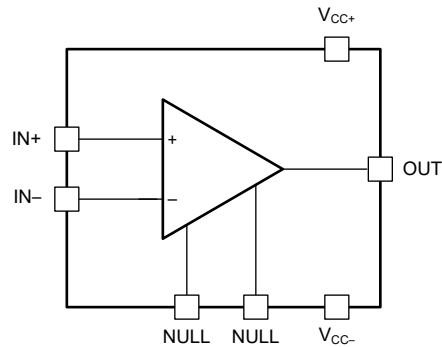
Figure 6-1. OPA891: Single Channel
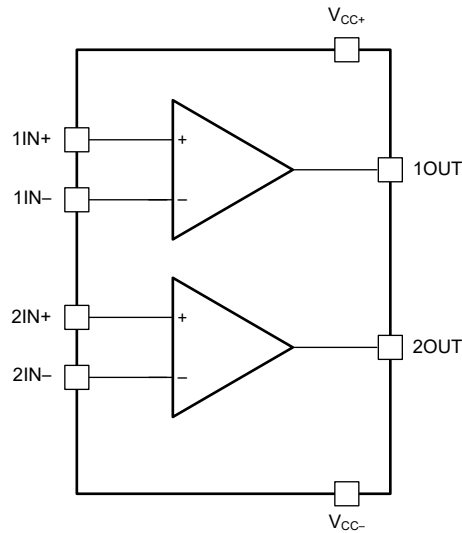
Figure 6-2. OPA2891: Dual Channel
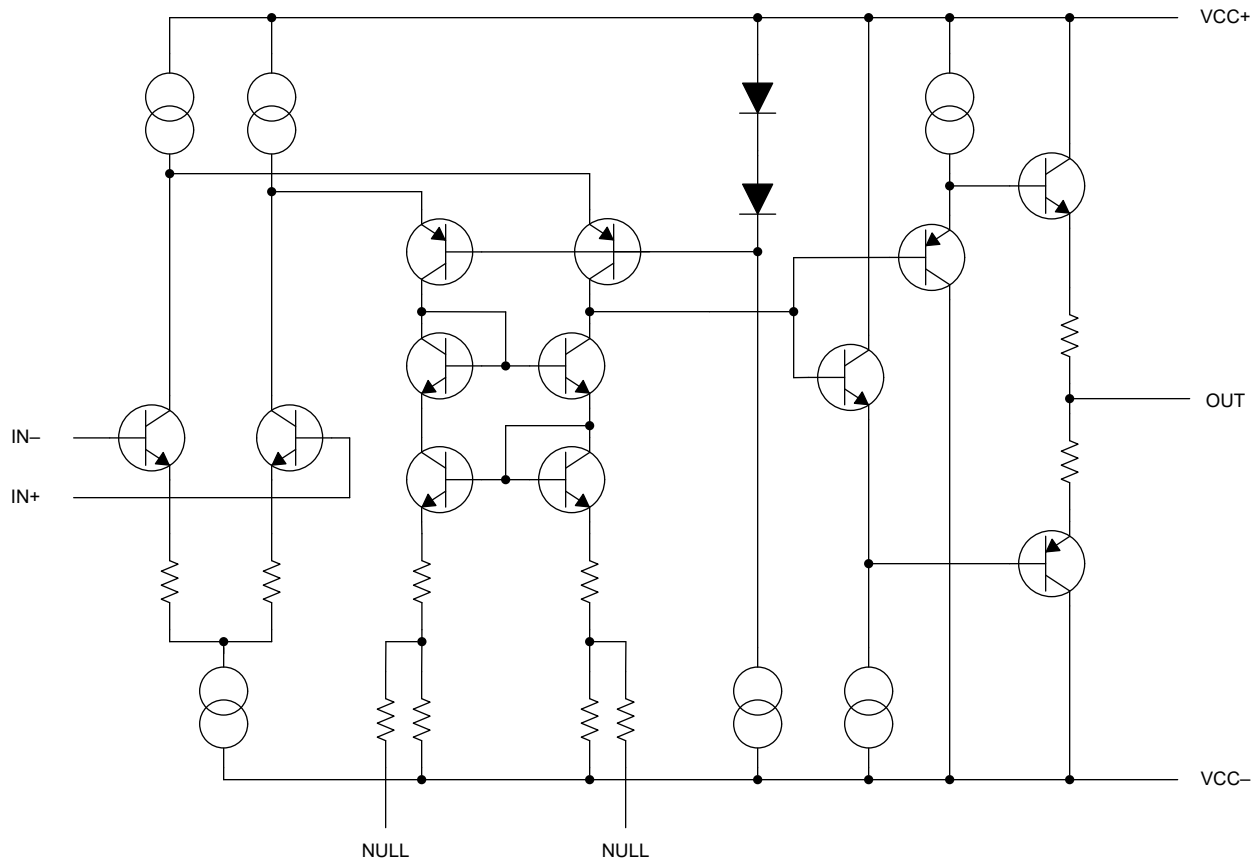
Figure 6-3. OPA891 Simplified Schematic

6.3 Feature Description

6.3.1 Offset Nulling

The OPAx891 have a very low input offset voltage for high-speed amplifiers. However, if additional correction is required, an offset nulling function is provided on the OPA891. To adjust the input offset voltage, place a potentiometer between pin 1 and pin 8 of the device, and tie the wiper to the negative supply. Figure 6-4 shows this feature.
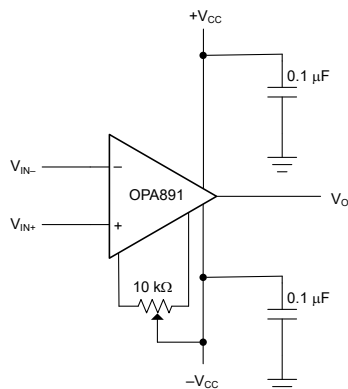
Figure 6-4. Offset Nulling Schematic

6.4 Device Functional Modes

The OPAx891 family has a single functional mode and can be used with both single-supply or split power-supply configurations. The power-supply voltage must be greater than 9V (±4.5V) and less than 36V (±18V).

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

7.1.1 Driving a Capacitive Load

The OPAx891 are internally compensated to maximize bandwidth and slew-rate performance. To maintain stability, take additional precautions when driving capacitive loads with a high-performance amplifier. As a result of the internal compensation, significant capacitive loading directly on the output node decreases the device phase margin, and potentially lead to high-frequency ringing or oscillations. Therefore, for capacitive loads greater than 10pF, place an isolation resistor in series with the output of the amplifier. Figure 7-1 shows this configuration. For most applications, a minimum resistance of 20Ω is recommended. In 75Ω transmission systems, setting the series resistor value to 75Ω is a beneficial choice because this value isolates any capacitance loading and provides source impedance matching.
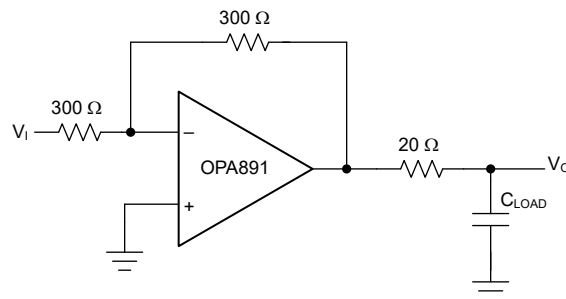

Figure 7-1. Driving a Capacitive Load

7.1.2 Low-Pass Filter Configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. Figure 7-2 shows how the simplest way to accomplish this limiting is to place an RC filter at the noninverting pin of the amplifier.
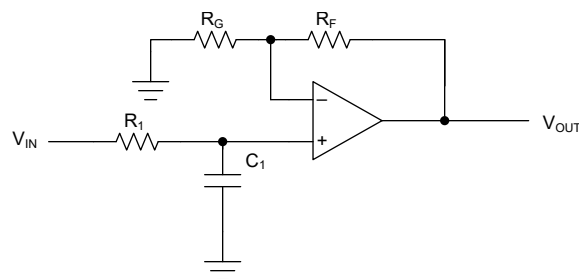
Figure 7-2. Single-Pole Low-Pass Filter

$$\frac{V_{OUT}}{V_{IN}} = \left(1 + \frac{R_F}{R_G}\right) \times \left(\frac{1}{1 + sR_1C_1}\right) \tag{1}$$

If more attenuation at higher frequencies is required, a multiple-pole filter is required. Figure 7-3 shows a common implementation of a second-order filter called a Sallen-Key filter. When designing this type of filter,

choose an amplifier with a bandwidth that is approximately an order of magnitude larger than the desired filter bandwidth. See Active Low-pass Filter Design for more detailed active-filter design information.

Assuming $R_1 = R_2 = R$ and $C_1 = C_2 = C$, use Equation 2 to set the bandwidth of the filter.

$$f_{3dB} = \frac{1}{2\pi RC} \tag{2}$$

The Q-factor of a filter controls the amount of peaking of the small-signal frequency response and the settling time of the pulse response. Set Q to 0.707 to provide a Butterworth response with a maximally-flat pass-band. Choose the ratio of R_F and R_G to obtain the desired Q value as shown in Equation 3.

$$\frac{R_F}{R_G} = 2 - \frac{1}{Q} \tag{3}$$
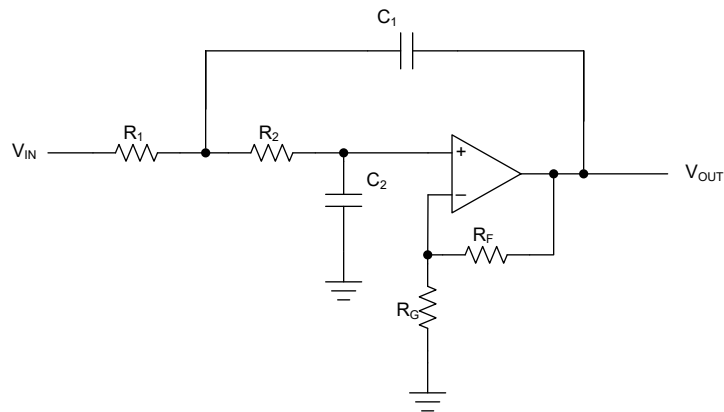
Figure 7-3. Two-Pole Low-Pass Sallen-Key Filter

Product Folder Links: *OPA891*

7.2 Typical Application

This section demonstrates multiplexing several analog input signals to a high-performance driver amplifier that subsequently drives a single, high-resolution, high-speed successive-approximation-register (SAR) analog-to-digital converter (ADC). This example uses the ADS8411 and the TS5A3159 or TS5A3359 as the ADC and the multiplexer, respectively. This application uses the OPAx891 as the operational amplifier.

Figure 7-4 details how the example system consists of an ADC (ADS8411), a driving operational amplifier (OPA891), a multiplexer (TS5A3159), an ac source, a dc source, and two driving operational amplifiers.

The driving amplifiers OPA1 and OPA2 are shown as two OPA891 amplifiers. Alternatively, use a single OPA2891 to save on cost and board space. The purpose of these op-amps is to make the input sources present a low impedance to rest of the circuit. Additionally, to maintain signal fidelity, these operational amplifiers must have low noise and distortion. The third OPA891, labeled OPA3 in Figure 7-4, is used to maintain switching speed and drive the ADC. The passive band-pass filter before the ADC reduces unwanted noise.
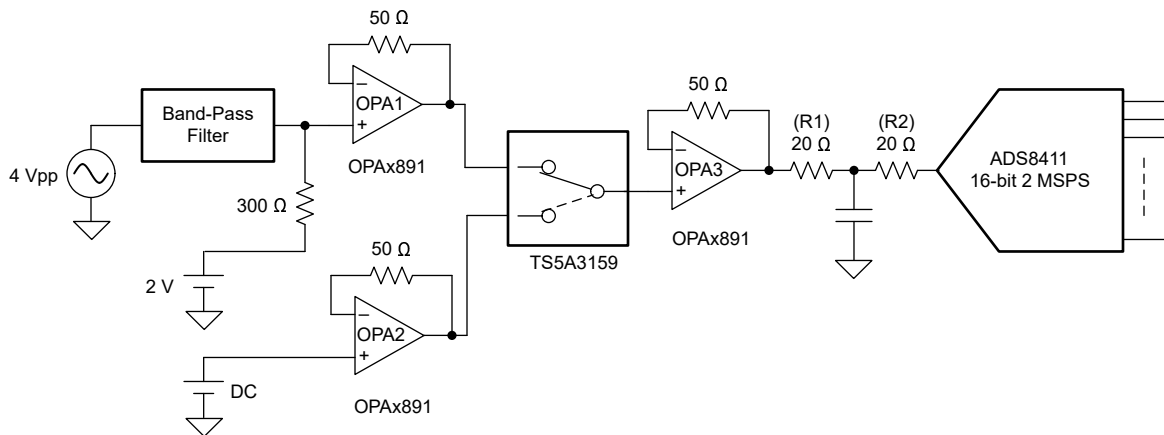
Figure 7-4. Multiplexing Set-Up to Drive a High-Performance ADC

7.2.1 Design Requirements

The objective is to design a multiplexed digitizer system with the dynamic performance shown in Table 7-1.

Table 7-1. Design Specifications

DEVICE SPEED (MSPS)	INPUT FREQUENCY (kHz)	SNR (dB)	THD (dB)	CROSSTALK (dB)
2	20	> 84	< –90	< –110
2	100	> 84	< –90	< –96

7.2.2 Detailed Design Procedure

The ADS8411 is a 16-bit, 2MSPS analog-to-digital converter (ADC) with a 4V reference. The ADS8411 has a unipolar single-ended input and includes a 16-bit capacitor-based SAR ADC, with inherent sample and hold. The output is a 16-bit parallel interface.

The TS5A3159 is a single-pole, double-throw (SPDT) analog switch that is designed to operate from 1.65V to 5.5V. The TS5A3159 offers a low on state resistance and an excellent on resistance matching with the break-before-make feature to prevent signal distortion during the transfer of a signal from one channel to another. Additionally, the TS5A3159 provides excellent total harmonic distortion (THD) performance and consumes low power. The TS5A3359 is a single-pole, triple-throw (SP3T) version of the same switch.

7.2.2.1 Selection of Multiplexer

Figure 7-5 shows an equivalent circuit diagram of one of the channels of a multiplexer. C_S is the input capacitance of the channel; C_D is the output capacitance of the channel. R_{ON} is the resistance of the channel when the channel is turned ON. C_L and R_L are the load capacitance and resistance, respectively. V_{IN} is the input voltage of the source. R_S is the resistance of the source. V_{OUT} is the output voltage of the multiplexer.

Figure 7-5. Multiplexer Equivalent Circuit

Settling time is improved when the values of R_S, R_{ON}, C_S, C_D, and C_L are small, and the value of R_L is large.

For TS5A3159:

- $R_{ON} = 1\Omega$
- $C_S = C_D = 84pF$

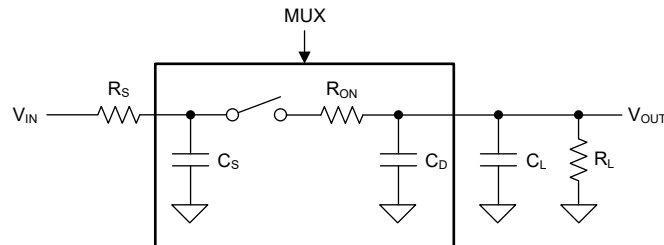Typical values for the extrinsic parameters are

- $R_S = 50\Omega$
- $C_L = 5pF$
- $R_L = 10k\Omega$
- T_{RC} (time constant) = 8.65ns

For a 16-bit system, at least 18-bit settling is desired to minimize distortion from settling artifacts. For a 18-bit settling, the circuit response time required is (18 × ln2) × T_{RC} = 108ns, which is less than 2MSPS sampling time of 500ns. If the settling time is more than the conversion time of the ADC, the output of the multiplexer does not settle to the required accuracy resulting in distortion.

One more important parameter to consider when selecting a multiplexer is the on-state resistance variation with voltage. This variation also affects distortion because R_{ON} and R_L act like a resistor divider circuit. Any variation of R_{ON} with voltage affects the output voltage.

7.2.2.2 Signal Source

The input signal source must be a low-noise, low-distortion source with low source resistance. As discussed in the earlier section, the source resistance also must be small to avoid impacting settling time. If the source is not a low-noise and low-distortion source, a passive band-pass filter can be added to improve the signal quality as shown in Figure 7-4.

7.2.2.3 Driving Amplifier

The driving operational amplifier (OPA3 in Figure 7-4) in this application must have good slew rate, bandwidth, low noise, and distortion. The input of the operational amplifier can result in a maximum step of 4V because of MUX switching. As a result, even if the signal bandwidth is low, the driving amplifier must settle from a 4V step within one ADC sampling frame to avoid signal distortion. In this example, the settling requirement due to the ADC selection is 500ns. The OPA891 is a good choice in this application due to the high slew rate and low distortion of this operational amplifier.

7.2.2.4 Driving Amplifier Bandwidth Restriction

Restricting excess bandwidth use by including a passive RC filter before the ADC results in better SNR and THD. However, restricting the bandwidth too much results in a excessive operational amplifier settling time. If the amplifier output does not settle quick enough, some residual charges from the previous channel remain in the next sampling interval and appear as crosstalk. One approach to solve this settling issue is to reduce the throughput of the ADC. However, the high sample rate ADC is often selected to meet the need to acquire higher frequency signals, limiting the freedom to reduce the ADC throughput. Due to these tradeoffs, the choice of the filter capacitor becomes critical. Figure 7-6 and Figure 7-7 show SNR and crosstalk as a function of the filter capacitor.

Figure 7-8 shows input settling behavior with three different filter capacitor values. The value of the capacitor changes to filter bandwidth. As the filter bandwidth increases, the settling time improves as shown in Equation 4.

$$\text{Filter Bandwidth} \cong \frac{1}{2\pi R_1 C_1} \qquad\qquad (4)$$

7.2.3 Application Curves

Figure 7-6. SNR vs Filter Capacitor

Figure 7-7. Crosstalk vs Filter Capacitor

Figure 7-8. Input to ADC for Various Values of Filter Capacitors
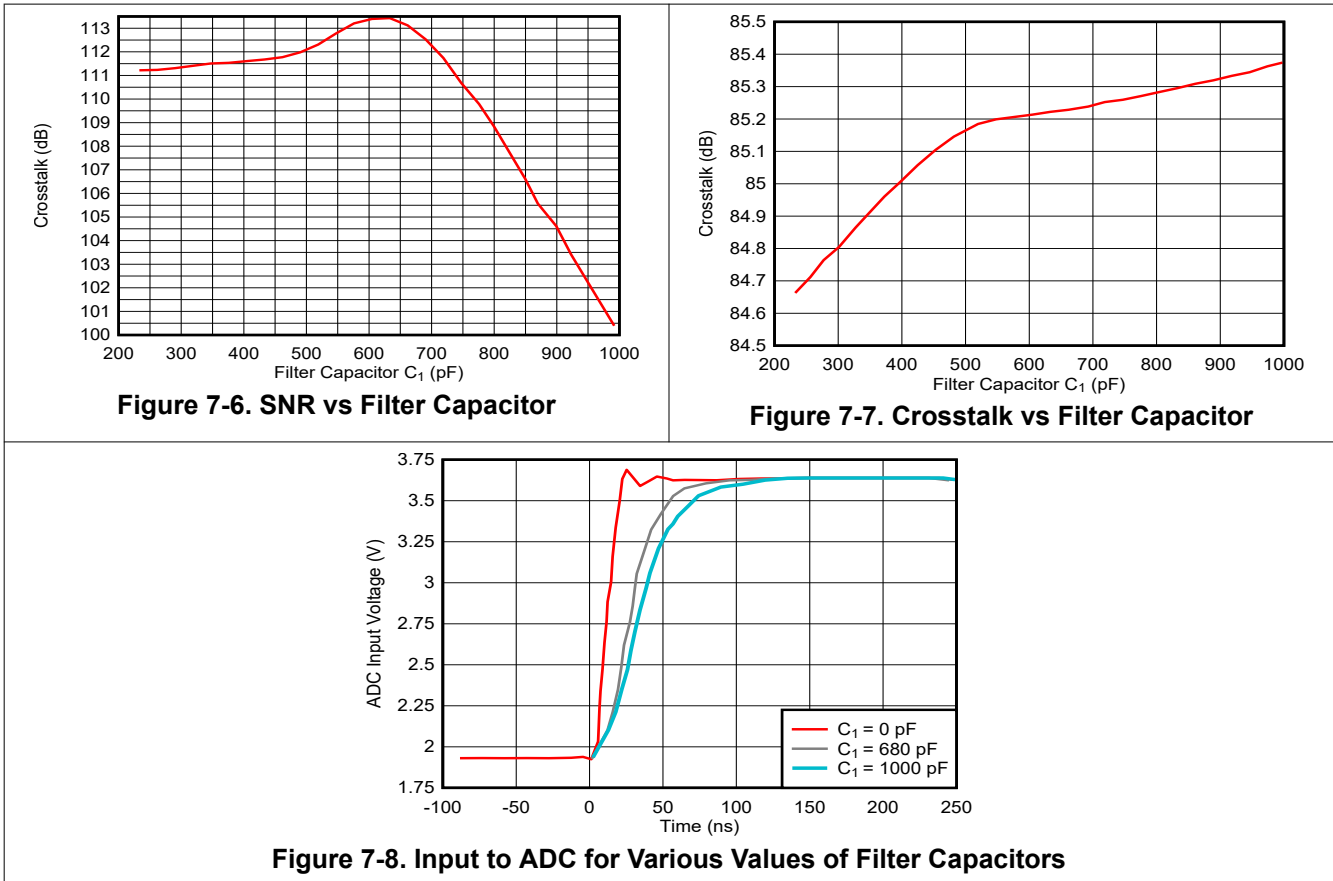
7.3 Power Supply Recommendations

The OPAx891 family operates with a single supply or with dual supplies. Choose supplies that provide for the required headroom to supply rails as specified by the common-mode input range (CMIR). Operating from a single supply has numerous advantages. With the negative supply at ground, the dc errors due to the –PSRR term are minimized. Decouple supplies as close to the amplifier as possible with low inductance capacitors decoupled to ground. When operating on a board with high-speed digital signals, provide isolation between digital signal noise and the analog input pins. When using a ground plane, remove the ground plane close to input sensitive pins to reduce stray parasitics that adversely impact device performance. For split-supply operation, an optional supply decoupling capacitor across the two power supplies improves second harmonic distortion performance.

7.4 Layout

7.4.1 Layout Guidelines

To achieve the levels of high-frequency performance of the OPAx891, follow proper printed-circuit board (PCB), high-frequency design techniques. The following is a general set of guidelines. In addition, a OPAx891 evaluation board is available to use as a guide for layout or for evaluating the device performance.

- **Ground planes**—make sure that the ground plane used on the board provides all components with a low-inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize stray capacitance.
- **Proper power-supply decoupling**—use a 6.8µF tantalum capacitor in parallel with a 0.1µF ceramic capacitor on each supply pin. Sharing the tantalum capacitor among several amplifiers is possible depending on the application, but always use a 0.1µF ceramic capacitor on the supply pin of every amplifier. In addition, place the 0.1µF capacitor as close as possible to the supply pin. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. Strive for distances of less than 0.1 inch (2.54mm) between the device power pins and the ceramic capacitors.
- **Short trace runs or compact part placements**—optimum high-frequency performance is achieved when stray series inductance has been minimized. To reduce stray series inductance, make the circuit layout as compact as possible, thereby minimizing the length of all trace runs. Focus attention on the inputs of the amplifier, keeping the trace lengths as short as possible. This layout helps to minimize stray capacitance at the input of the amplifier.
- **Sockets**—TI does not recommend sockets for high-speed operational amplifiers. The additional lead inductance in the socket pins often leads to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- **Short trace runs and compact part placements**—Improved high-frequency performance is achieved when stray series inductance is minimized. To reduce stray series inductance, the circuit layout must be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention must be provided to the inverting input of the amplifier. The length must be kept as short as possible. This design decision helps minimize stray capacitance at the input of the amplifier.

7.4.1.1 General PowerPAD™ Integrated Circuit Package Design Considerations

The OPAx891 is available in a thermally-enhanced DGN package, which is a member of the PowerPAD™ integrated circuit package family. This package is constructed using a downset lead frame upon which the die is mounted [see Figure 7-9(a) and Figure 7-9(b)]. This arrangement results in the lead frame exposed as a thermal pad on the underside of the package [see Figure 7-9(c)]. Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

The PowerPAD™ integrated circuit package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are soldered), the thermal pad can be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat is conducted away from the package into a ground plane or other heat-dissipating device.

The PowerPAD™ integrated circuit package represents a breakthrough in combining the small area and ease of assembly of surface mount with the heretofore awkward mechanical methods of sinking heat.
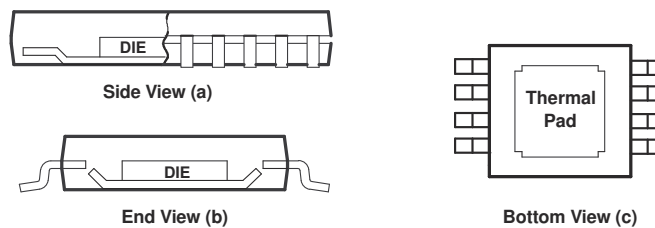
Note: The thermal pad is electrically isolated from all pins in the package.

Figure 7-9. Views of Thermally-enhanced DGN Package

Although there are many ways to properly dissipate heat in this device, the following steps show the recommended approach.

Thermal pad area (68 mils x 70 mils) with 5 vias
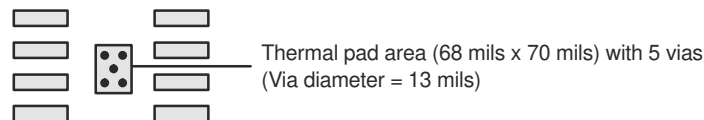(Via diameter = 13 mils)

Figure 7-10. PowerPAD™ Integrated Circuit Package PCB Etch and Via Pattern

1. Prepare the PCB with a top-side etch pattern as shown in Figure 7-10. There must be etch for the leads as well as etch for the thermal pad.
2. Place five holes in the area of the thermal pad. These holes must be 13 mils (0.3302mm) in diameter. The reason to keep the holes small is to discourage solder wicking through the holes during reflow.
3. Additional vias can be placed anywhere along the thermal plane outside of the thermal pad area. This action helps dissipate the heat generated by the OPAx891 device. The additional vias can be of any diameter because wicking is not a concern outside of the thermal pad area.
4. Connect all holes to the internal ground plane.
5. When connecting these holes to the ground plane, *do not* use the typical web or spoke via connection methodology. Web connections have a high thermal-resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the OPAx891 package must connect to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.
6. The top-side solder mask must leave the pins of the package and the thermal pad area with the five holes exposed. The bottom-side solder mask must cover the five holes of the thermal pad area, which prevents solder from pulling away from the thermal pad area during the reflow process.
7. Apply solder paste to the exposed thermal pad area and to all the device pins.
8. With these preparatory steps in place, the OPAx891 device is placed in position and run through the solder reflow operation as any standard surface-mount component.
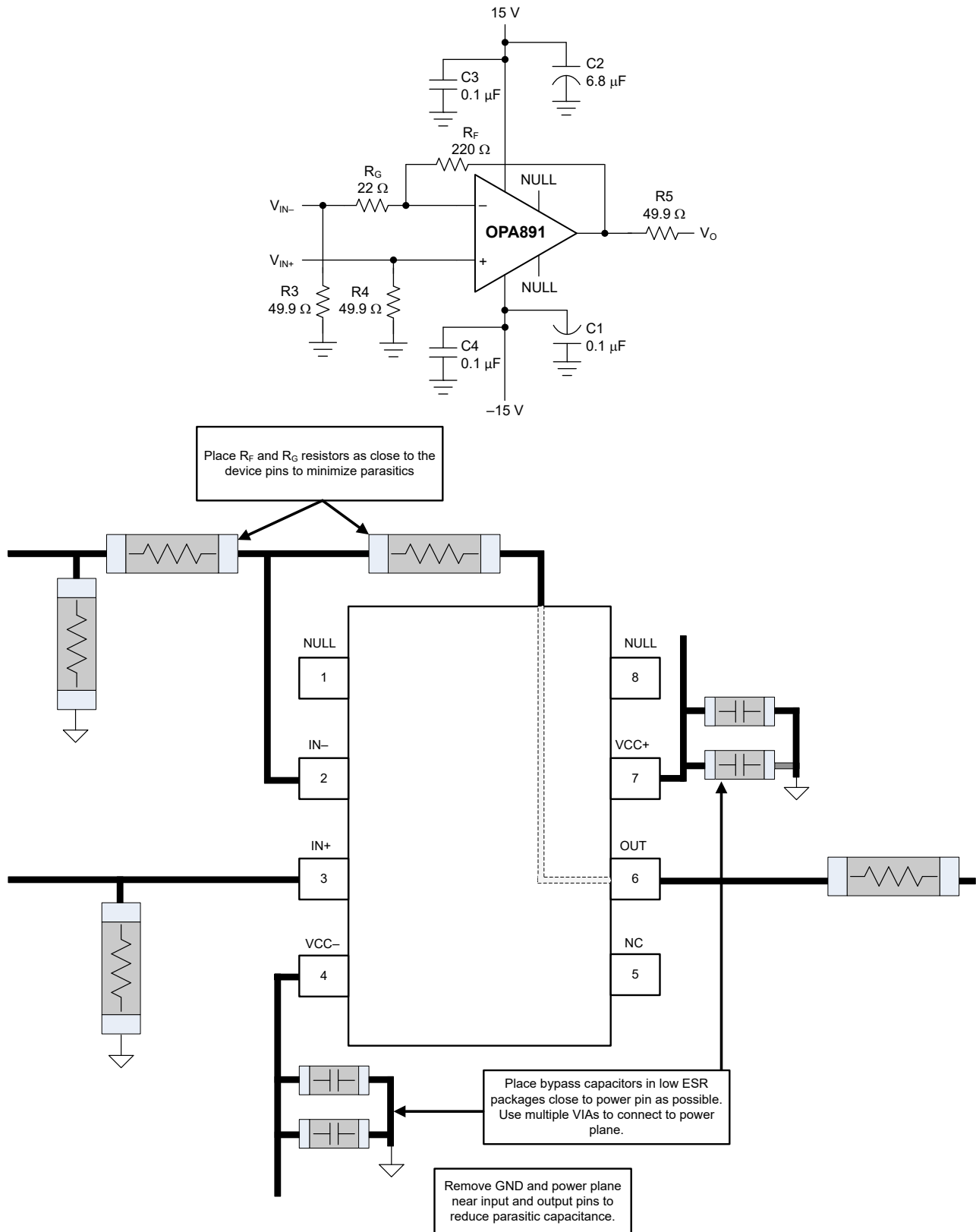
7.4.2 Layout Example

Figure 7-11. Layout Recommendations

Product Folder Links: *OPA891*

8 Device and Documentation Support

8.1 Documentation Support

8.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, *Noise Analysis for High-Speed Op Amps* application note
- Texas Instruments, *PowerPAD™ Thermally Enhanced Package* application note
- Texas Instruments, *DEM-OPA-SO-1A Demonstration Fixture* user's guide
- Texas Instruments, *DEM-OPA-SO-2A Demonstration Fixture* user's guide
- Texas Instruments, *DEM-OPA-MSOP-2A Demonstration Fixture* user's guide

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.4 Trademarks

PowerPAD™ and TI E2E™ are trademarks of Texas Instruments.
All trademarks are the property of their respective owners.

8.5 Electrostatic Discharge Caution

![ESD warning symbol]

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary   This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
OPA891DGNR	ACTIVE	HVSSOP	DGN	8	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	O891	Samples
OPA891DR	ACTIVE	SOIC	D	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	O891	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

Reel Diameter

Reel Width (W1)

TAPE DIMENSIONS

Cavity

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

Sprocket Holes

User Direction of Feed

Pocket Quadrants

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA891DGNR	HVSSOP	DGN	8	3000	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA891DR	SOIC	D	8	3000	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA891DGNR	HVSSOP	DGN	8	3000	356.0	356.0	35.0
OPA891DR	SOIC	D	8	3000	356.0	356.0	35.0

DGN 8

3 x 3, 0.65 mm pitch

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.
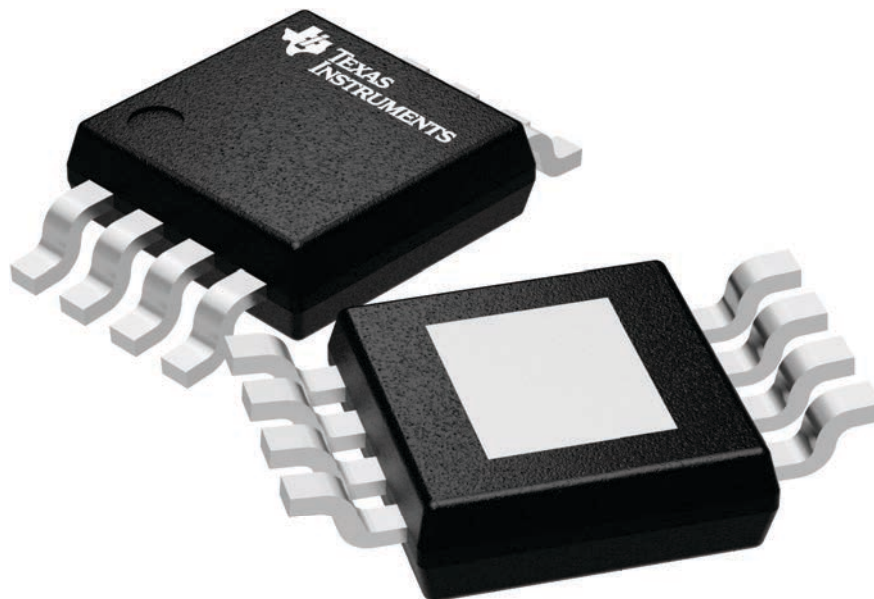
4225482/A
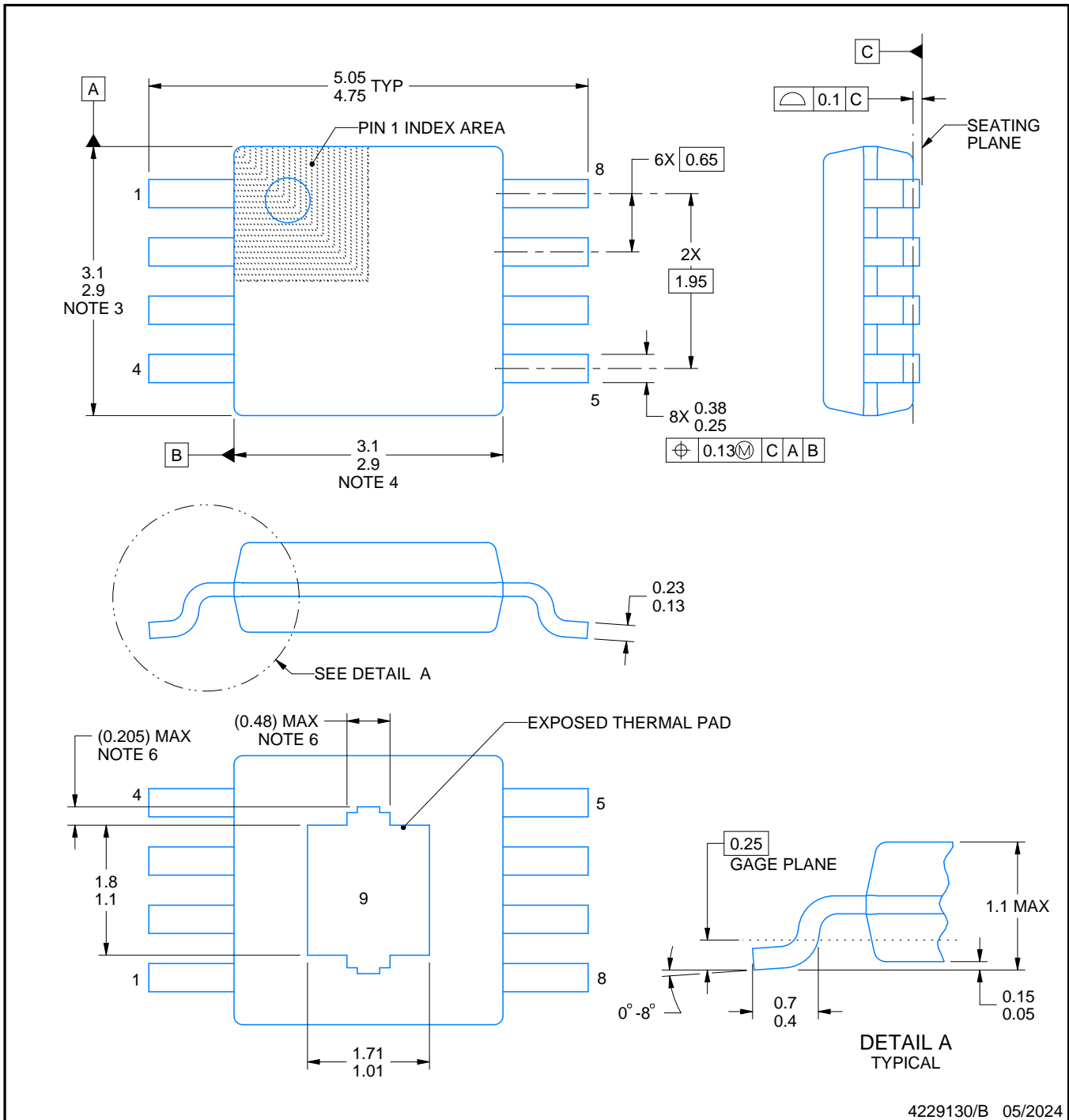
4229130/B   05/2024

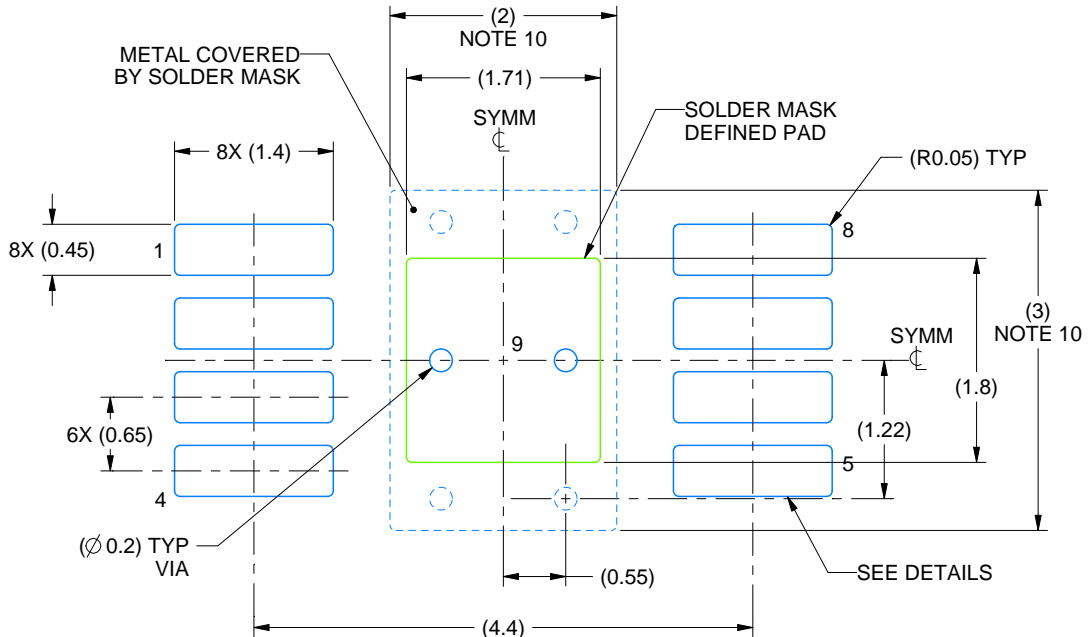PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.
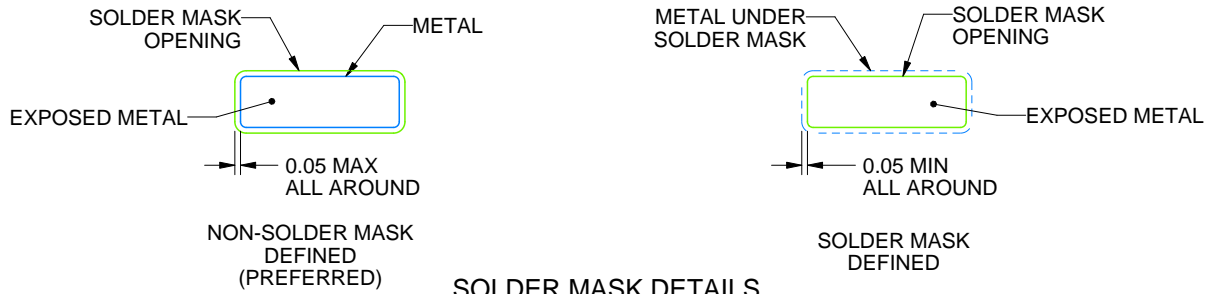6. Features may differ or may not be present.

METAL COVERED
BY SOLDER MASK

(2)
NOTE 10

(1.71)

SYMM

SOLDER MASK
DEFINED PAD

(R0.05) TYP

8X (1.4)

8X (0.45)   1

8

9

SYMM

(3)
NOTE 10

(1.8)

6X (0.65)

(1.22)

4

5

(⌀ 0.2) TYP
VIA

(0.55)

SEE DETAILS

(4.4)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.05 MIN
ALL AROUND

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4229130/B   05/2024

NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.
8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
9. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown
on this view. It is recommended that vias under paste be filled, plugged or tented.
10. Size of metal pad may vary due to creepage requirement.

DGN0008H

PowerPAD™ VSSOP - 1.1 mm max height

(1.71)
BASED ON
0.125 THICK
STENCIL

SYMM

(R0.05) TYP

8X (1.4)

8X (0.45)   1

8

SYMM

(1.8)
BASED ON
0.125 THICK
STENCIL

6X (0.65)

4

5

METAL COVERED
BY SOLDER MASK

(4.4)

SEE TABLE FOR
DIFFERENT OPENINGS
FOR OTHER STENCIL
THICKNESSES
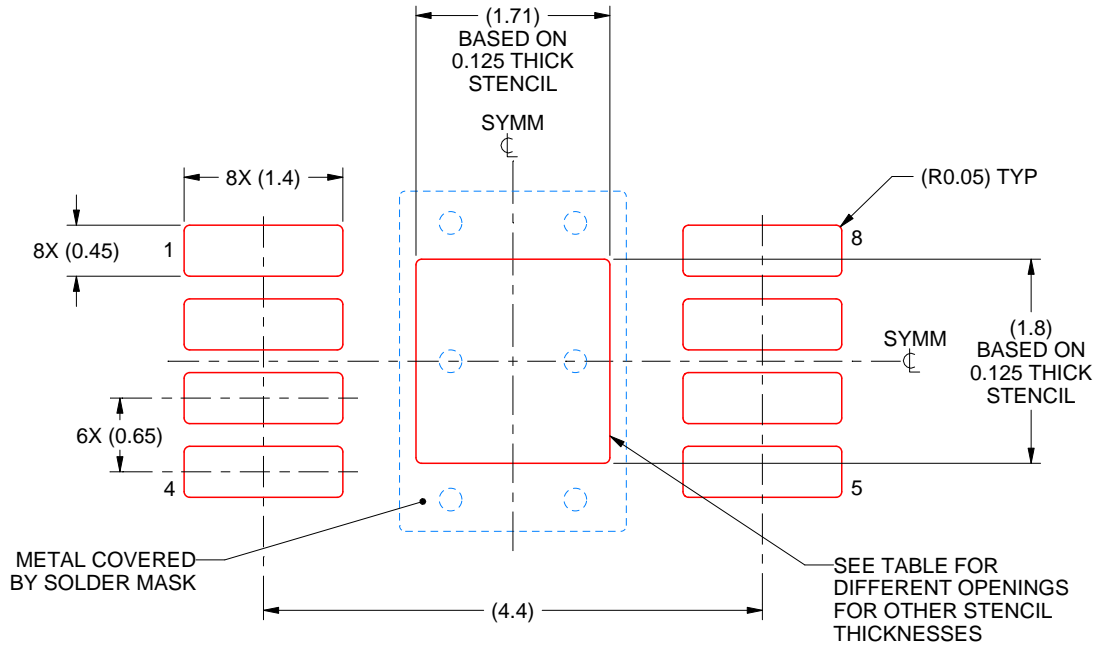
SOLDER PASTE EXAMPLE
EXPOSED PAD 9:
100% PRINTED SOLDER COVERAGE BY AREA
SCALE: 15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	1.91 X 2.01
0.125	1.71 X 1.80 (SHOWN)
0.15	1.56 X 1.64
0.175	1.45 X 1.52

4229130/B 05/2024

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

TEXAS
INSTRUMENTS
www.ti.com

C

SEATING PLANE

.004 [0.1] C

.228-.244 TYP
[5.80-6.19]

A

PIN 1 ID AREA

6X .050
[1.27]

1

8

2X
.150
[3.81]

.189-.197
[4.81-5.00]
NOTE 3

4

5

4X (0°-15°)

8X .012-.020
[0.31-0.51]

B

.150-.157
[3.81-3.98]
NOTE 4

.010 [0.25] Ⓜ C A B

.069 MAX
[1.75]

SEE DETAIL A

4X (0°-15°)

.005-.010 TYP
[0.13-0.25]

.010
[0.25]

0°- 8°

.016-.050
[0.41-1.27]

(.041)
[1.04]

.004-.010
[0.11-0.25]

DETAIL A
TYPICAL

4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches.
   Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
   exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

TEXAS
INSTRUMENTS
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8X (.061)
[1.55]

SYMM
℄

SEE
DETAILS

1

8

8X (.024)
[0.6]

SYMM
℄

(R.002) TYP
[0.05]

4

5

6X (.050)
[1.27]

(.213)
[5.4]

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X

METAL

SOLDER MASK
OPENING

SOLDER MASK
OPENING

METAL UNDER
SOLDER MASK

EXPOSED
METAL

EXPOSED
METAL

.0028 MAX
[0.07]
ALL AROUND

.0028 MIN
[0.07]
ALL AROUND

NON SOLDER MASK
DEFINED

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4214825/C   02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

8X (.061)
[1.55]

1

8X (.024)
[0.6]

6X (.050)
[1.27]

4

SYMM

8

SYMM

5

(R.002) TYP
[0.05]

(.213)
[5.4]

SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C   02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.